

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/796,824	03/09/2004	Wei Wang	AM-6535.D1	2457
7590 02/01/2006			EXAMINER	
Applied Materials, Inc.			MCDONALD, RODNEY GLENN	
	Dept., M/S 2061		A DELLO VIE	0.000.000
P.O. Box 450A			ART UNIT	PAPER NUMBER
Santa Clara, CA 95052			1753	

DATE MAILED: 02/01/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	10/796,824	WANG, WEI					
Office Action Summary	Examiner	Art Unit					
•	Rodney G. McDonald	1753					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period versions of the period of the period for reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timused and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	I. nely filed the mailing date of this communication. D (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on 23 No.	ovember 2005.						
	action is non-final.						
3) Since this application is in condition for allowar	nce except for formal matters, pro	secution as to the merits is					
closed in accordance with the practice under E							
Disposition of Claims							
4) Claim(s) 1-18 is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-18</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/o	r election requirement.						
Application Papers							
9) The specification is objected to by the Examiner.							
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Ex							
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document: 2. Certified copies of the priority document: 3. Copies of the certified copies of the priority document: application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applicati rity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage					
Attachment(s)	_						
1) Notice of References Cited (PTO-892)	4) Interview Summary Paper No(s)/Mail Da						
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 		ratent Application (PTO-152)					

Art Unit: 1753

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on November 23, 2005 has been entered.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Art Unit: 1753

Claims 1, 4, 5 and 10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Fai Lai (U.S. Pat. 6,217,716) in view of Wegmann (U.S. Pat. 4,622,121) or Scherer (U.S. Pat. 5,728,280) or Okamura et al. (Japan 01-309964).

Fai Lai '716 teach a vault shaped sputtering target as seen in Fig. 10. Fai Lai '716 teach a principal target in the form of a hollow cathode 132 for sputtering that has a sidewall and roof shaped like a vault. A magnetic means 129 surrounds the sidewall of the cathode. A rotating magnet 126 is positioned on the back side of the roof and is rotatable about the central axis. The magnet polarity of magnet 129 extends along the central axis. (Fig. 10; Column 8 lines 30-49) The cathode can sputter target material on substrates. (Column 1 line 30)

The differences between Fai Lai '716 and the present claims is that the magnetic means positioned outside the cylindrically shaped sidewall and extending around the central axis but not extending above a plane extending perpendicular to the central axis at a back of the roof is not discussed.

Regarding the magnetic means positioned outside the cylindrically shaped sidewall and extending around the central axis but not extending above a plane extending perpendicular to the central axis at a back of the roof, Wegmann et al. teach in Fig. 1 a magnetic means not extending above a roof of the target. (See Fig. 1) Scherer teach a magnetic means 12 not extending above a roof of the target. (See Abstract; Figure) Okamura et al. teach in Figure 1 a magnetic means not extending above a roof of the target. (See Figure 1)

Art Unit: 1753

The motivation for providing a magnetic means not extending above a roof of the target is that it allows for improving step coating (Wegmann et al. Column 2 lines 43-46), permit low energy deposition (Scherer Column 1 lines 39-40) and form a film with uniform characteristics. (See Okamura et al. Abstract)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have modified Fai Lai '716 by utilizing magnet means not extending above a rood of the target as taught by Wegmann et al. or Scherer or Okamura et al. because it allows for improving step coating, permitting low energy deposition and forming a film with uniform characteristics.

Claims 1, 4, 5, 6, 10 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lai et al. (U.S. Pat. 6,444,105) in view of Wegmann (U.S. Pat. 4,622,121) or Scherer (U.S. Pat. 5,728,280) or Okamura et al. (Japan 01-309964).

Lai et al. '105 teach in Fig. 3A a vault shaped hollow cathode for sputtering. Magnet means are present in the form of magnets 11 stacked in-between iron shims 12 arranged along the sidewalls of the cathode. Magnets 11 are oriented to generate magnetic flux in the axial (or Z) direction. Top pole piece 207 and bottom pole piece 205 are placed on the north and south sides of permanent magnet array 5, respectively, to direct and focus magnet field lines. A rotating magnet array 6 located at the back of the roof of the hollow cathode is provided. (Figure 3A; Column 5 lines 59-68; Column 6 lines 1-2) The hollow cathode can be utilized to sputter on a substrate 2. (Column 3 lines 22-24)

Art Unit: 1753

The differences between Lai et al. '105 and the present claims is that the magnetic means positioned outside the cylindrically shaped sidewall and extending around the central axis but not extending above a plane extending perpendicular to the central axis at a back of the roof is not discussed.

Regarding the magnetic means positioned outside the cylindrically shaped sidewall and extending around the central axis but not extending above a plane extending perpendicular to the central axis at a back of the roof, Wegmann et al. teach in Fig. 1 a magnetic means not extending above a roof of the target. (See Fig. 1) Scherer teach a magnetic means 12 not extending above a roof of the target. (See Abstract; Figure) Okamura et al. teach in Figure 1 a magnetic means not extending above a roof of the target. (See Figure 1)

The motivation for providing a magnetic means not extending above a roof of the target is that it allows for improving step coating (Wegmann et al. Column 2 lines 43-46), permit low energy deposition (Scherer Column 1 lines 39-40) and form a film with uniform characteristics. (See Okamura et al. Abstract)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have modified Fai Lai '716 by utilizing magnet means not extending above a roof of the target as taught by Wegmann et al. or Scherer or Okamura et al. because it allows for improving step coating, permitting low energy deposition and forming a film with uniform characteristics.

Art Unit: 1753

Claims 2, 3 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lai '716 in view of Wegmann or Scherer or Okamura et al. as applied to claims 1

and 10 above, and further in view of Gopalraja et al. (EP 1119017).

The differences not yet discussed is the magnetron comprising a first magnet assembly of a first magnetic polarity along the central axis and a second magnet assembly of a second magnetic polarity opposite the first magnet polarity and surrounding the first magnet assembly, where the plurality of magnets arranged around an exterior of the sidewall have the second magnetic polarity, a vacuum chamber and a pedestal for supporting a substrate in the vacuum chamber.

Gopalraja et al. teach in Fig. 13 a scanning magnetron on the roof of a target having a first magnet 240 with a first magnetic polarity along the central axis and a second magnet 238 surrounding the first magnet and having a second magnetic polarity. The magnet 222 surrounding the sidewall has the second magnetic polarity. (See Fig. 13; Column 19 lines 4-9, lines 26-32) The cathode can be in a sputter reactor 10 with a wafer clamped to a pedestal electrode 54. (Column 11 line 32, line 40-43)

The motivation for selecting the magnets to be a particular order is that it allows for achieving a desired erosion pattern. (Column 19 lines 20-22)

The motivation for utilizing a sputter reactor and pedestal is that it allows for sputtering on the wafer for via filling. (Column 1 lines 5-7)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized a first magnet assembly of a first magnetic polarity along the central axis and a second magnet assembly of a second magnetic

Art Unit: 1753

polarity opposite the first magnet polarity and surrounding the first magnet assembly, arranging the plurality of magnets around an exterior of the sidewall having the second magnetic polarity, utilized a vacuum chamber and utilized a pedestal for supporting a substrate in the vacuum chamber as taught by Gopalraja et al. because it allows for achieving a desired erosion pattern and for sputtering on the wafer for via filling.

Claims 2, 3, 8, 13 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lai '105 in view of Wegmann or Scherer or Okamura et al. as applied to claims 1, 10 and 12 above, and further in view of Gopalraja et al. (EP 1119017).

The differences not yet discussed is the magnetron comprising a first magnet assembly of a first magnetic polarity along the central axis and a second magnet assembly of a second magnetic polarity opposite the first magnet polarity and surrounding the first magnet assembly, where the plurality of magnets arranged around an exterior of the sidewall have the second magnetic polarity, a vacuum chamber and a pedestal for supporting a substrate in the vacuum chamber.

Gopalraja et al. teach in Fig. 13 a scanning magnetron on the roof of a target having a first magnet 240 with a first magnetic polarity along the central axis and a second magnet 238 surrounding the first magnet and having a second magnetic polarity. The magnet 222 surrounding the sidewall has the second magnetic polarity. (See Fig. 13; Column 19 lines 4-9, lines 26-32) The cathode can be in a sputter reactor 10 with a wafer clamped to a pedestal electrode 54. (Column 11 line 32, line 40-43)

The motivation for selecting the magnets to be a particular order is that it allows for achieving a desired erosion pattern. (Column 19 lines 20-22)

Art Unit: 1753

The motivation for utilizing a sputter reactor and pedestal is that it allows for sputtering on the wafer for via filling. (Column 1 lines 5-7)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized a first magnet assembly of a first magnetic polarity along the central axis and a second magnet assembly of a second magnetic polarity opposite the first magnet polarity and surrounding the first magnet assembly, arranging the plurality of magnets around an exterior of the sidewall having the second magnetic polarity, utilized a vacuum chamber and utilized a pedestal for supporting a substrate in the vacuum chamber as taught by Gopalraja et al. because it allows for achieving a desired erosion pattern and for sputtering on the wafer for via filling.

Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Fai Lai '716 or Lai '105 in view of Wegmann or Scherer or Okamura et al. as applied to claim 1 above, and further in view of Haag et al. (U.S. Pat. 6,337,001), Glocker et al. (U.S. Pat. 5,069,770) and Kumar (U.S. Pat. 5,178,743).

The differences not yet discussed is that utilizing a plate comprising the material and closing a throat of the vault opposite the roof is not discussed.

Haag et al. teach in Figure 8 annular plates with a partially closed throat. (See Figure 8) In Fig. 2 the plates 8a close a throat of a target. (See Fig. 2) Figure 5 shows the target can be annular. (See Figure 5; Column 5 line 2)

The motivation for utilizing a closed throat is that it increase plasma density within the hollow target. (Column 3 lines 2-3)

Art Unit: 1753

Glocker teach a sputtering process which employs a target which defines a hollow sputtering chamber having a relatively small orifice or slit through which particles, sputtered from the chamber-defining interior surfaces of the target, can exit the chamber and deposit on a workpiece or substrate disposed externally of the chamber and facing the orifice. (See Abstract)

A preferred enclosed target is in the form of a hollow cylinder with a circular hole in one end. The outside diameter of the cylinder is 7.4 cm, and the height is 4 cm. The inside diameter of the sputtering chamber is 4.6 cm and the height of such chamber is 2 cm. The hole has a diameter of about 1 cm. (Column 3 lines 1-6)

The motivation for utilizing a closed throat is that it confines the plasma. (Column 2 line 55)

Kumar teach a cathode 4 comprises a container element 30, top 32 and means 34 for connecting the top 32 to container element 30. This latter means is shown as a plurality of screws 34 driven through an equal number of holes through the top 32 into corresponding tapped holes in the container element 30. Of course other means for connecting top 32 to container element 30 may be employed. For example, top 32 and container element 30 may be provided with engaging threads or interlocking slots and notches. It is within the scope of the present invention to employ any conventional connecting means to connect top 32 to container element 30. (Column 5 lines 23-34)

The top 32, which needs to be only slightly large than the major opening of the container element 30, has a diameter in the actually constructed embodiment which is about equal to the outer cylindrical diameter of container element 30, that is, two and

Art Unit: 1753

one-half inches. The top 32 is about one eighth inch thick, as is the bottom portion 38 of the container element 30. The top 32, like the container element 30, also has a central axial hole 39 extending therethrough within is about one half inch in diameter. The top 32 and the container element 30 were formed of copper by conventional techniques. (Column 5 lines 55-68; Column 6 lines 1-6)

The motivation utilizing an attached plate to close the throat is that it allows for confinement of plasma and easier of removal of the cathode 30 for replacement. (See Figure 3)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized a closed throat of a sputtering target and closing the throat by an attachable plate as taught by the combination of Haag et al., Glocker et al. and Kumar because it allows for confining the plasma.

Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lai '716 in view of Wegmann or Scherer or Okamura et al. and further in view of Gopalraja et al. as applied to claim 8 above, and further in view of Haag et al. (U.S. Pat. 6,337,001).

The difference not yet discussed is the use of an anode between the target and the substrate.

Haag et al. suggest an anode 8a in Fig. 2 that is positioned between the target and the substrate. (i.e. see Fig. 9 for positional relationship of the target and the substrate). The anode is bias able to control particle energy. (See Fig. 2; Column 4 lines 16-27)

Art Unit: 1753

The motivation for utilizing an anode is that it allows for control of particles. (See Column 4 lines 16-27)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized an anode as taught by Haag et al. because it allows control of particles.

Claims 11 and 15-18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lai et al. '105 in view of Wegmann or Scherer or Okamura et al. and further in view of Gopalraja et al. as applied to claims 8, 12 and 14 above, and further in view of Haaq et al. (U.S. Pat. 6,337,001).

The difference not yet discussed is the use of an anode between the target and the substrate.

Haag et al. suggest an anode 8a in Fig. 2 that is positioned between the target and the substrate. (i.e. see Fig. 9 for positional relationship of the target and the substrate). The anode is bias able to control particle energy. (See Fig. 2; Column 4 lines 16-27)

The motivation for utilizing an anode is that it allows for control of particles. (See Column 4 lines 16-27)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized an anode as taught by Haag et al. because it allows control of particles.

Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Fai Lai '716 or Lai et al. '105 in view of Wegmann or Scherer or Okamura et al. and further in

Art Unit: 1753

view of Gopalraja et al. as applied to claim 8 above, and further in view of Glocker et al. (U.S. Pat. 5,069,770).

The difference not yet discussed is where the magnetic means do not extend beyond a front sputtering surface of the roof.

Glocker et al. teach a magnetic means 20 not extending beyond a front face of the target. (Column 2 lines 42-45; Fig. 1)

The motivation for utilizing a magnetic means that does not extend beyond the front face surface of the target is that it allows for decreasing the number of high energy electrons escaping from the sputtering chamber during sputtering. (Column 1 lines 50-55)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized a magnetic means that does not extend beyond the front surface of the target as taught by Glocker et al. because it allows for decreasing the number of high energy electrons escaping form the sputtering chamber during sputtering.

Response to Arguments

Applicant's arguments filed November 23, 2005 have been fully considered but they are not persuasive.

In response to the argument that the prior art does not teach the magnets located above the roof, it is argued that the secondary references to Wegmann, Scherer and Okamura et al. teach locating magnetic means above the roof of the targets.

Art Unit: 1753

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Rodney G. McDonald whose telephone number is 571-272-1340. The examiner can normally be reached on M- Th with Every other Friday off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X. Nguyen can be reached on 571-272-1342. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Rodney G. McDonald Primary Examiner Art Unit 1753

RM January 23, 2006